



PSMN1R1-30PL

N-channel 30 V 1.3 m Ω logic level MOSFET in TO-220

2 April 2014

Product data sheet

1. General description

Logic level N-channel MOSFET in TO-220 package qualified to 175 °C. This product is designed and qualified for use in a wide range of industrial, communications and domestic equipment.

2. Features and benefits

- High efficiency due to low switching and conduction losses
- Suitable for logic level gate drive sources

3. Applications

- DC-to-DC converters
- Load switching
- Motor control
- Server power supplies

4. Quick reference data

Table 1. Quick reference data

| Symbol | Parameter | Conditions | | Min | Typ | Max | Unit |
|--------------------------------|----------------------------------|--|-----|-----|-----|-----|------------|
| V _{DS} | drain-source voltage | T _j ≥ 25 °C; T _j ≤ 175 °C | | - | - | 30 | V |
| I _D | drain current | T _{mb} = 25 °C; V _{GS} = 10 V; Fig. 2 | [1] | - | - | 120 | A |
| P _{tot} | total power dissipation | T _{mb} = 25 °C; Fig. 1 | | - | - | 338 | W |
| T _j | junction temperature | | | -55 | - | 175 | °C |
| Static characteristics | | | | | | | |
| R _{DSon} | drain-source on-state resistance | V _{GS} = 10 V; I _D = 25 A; T _j = 25 °C; Fig. 12 | [2] | - | 1.1 | 1.3 | m Ω |
| | | V _{GS} = 10 V; I _D = 25 A; T _j = 100 °C; Fig. 13 | | - | 1.5 | 1.8 | m Ω |
| Dynamic characteristics | | | | | | | |
| Q _{GD} | gate-drain charge | V _{GS} = 4.5 V; I _D = 75 A; V _{DS} = 15 V; Fig. 14 ; Fig. 15 | | - | 37 | - | nC |
| Q _{G(tot)} | total gate charge | | | - | 118 | - | nC |

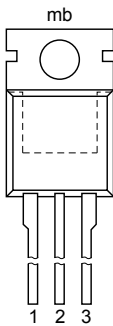
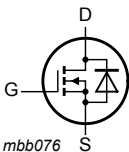
| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|-----------------------------|--|---|-----|-----|-----|------|
| Avalanche ruggedness | | | | | | |
| $E_{DS(AL)S}$ | non-repetitive drain-source avalanche energy | $V_{GS} = 10\text{ V}$; $T_{j(\text{init})} = 25\text{ °C}$; $I_D = 120\text{ A}$; $V_{\text{sup}} \leq 30\text{ V}$; $R_{GS} = 50\text{ }\Omega$; unclamped | - | - | 1.9 | J |

[1] Continuous current is limited by package.

[2] Measured 3 mm from package.

5. Pinning information

Table 2. Pinning information

| Pin | Symbol | Description | Simplified outline | Graphic symbol |
|-----|--------|-----------------------------------|---|--|
| 1 | G | gate |  <p style="text-align: center;">TO-220AB (SOT78)</p> |  <p style="text-align: center;"><i>mbb076</i></p> |
| 2 | D | drain | | |
| 3 | S | source | | |
| mb | D | mounting base; connected to drain | | |

6. Ordering information

Table 3. Ordering information

| Type number | Package | | |
|--------------|----------|--|---------|
| | Name | Description | Version |
| PSMN1R1-30PL | TO-220AB | plastic single-ended package; heatsink mounted; 1 mounting hole; 3-lead TO-220AB | SOT78 |

7. Marking

Table 4. Marking codes

| Type number | Marking code |
|--------------|--------------|
| PSMN1R1-30PL | PSMN1R1-30PL |

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | | Min | Max | Unit |
|-----------------------------|--|--|-----|-----|------|------|
| V_{DS} | drain-source voltage | $T_j \geq 25\text{ °C}; T_j \leq 175\text{ °C}$ | | - | 30 | V |
| V_{DGR} | drain-gate voltage | $T_j \geq 25\text{ °C}; T_j \leq 175\text{ °C}; R_{GS} = 20\text{ k}\Omega$ | | - | 30 | V |
| V_{GS} | gate-source voltage | | | -20 | 20 | V |
| P_{tot} | total power dissipation | $T_{mb} = 25\text{ °C}; \text{Fig. 1}$ | | - | 338 | W |
| I_D | drain current | $V_{GS} = 10\text{ V}; T_{mb} = 100\text{ °C}; \text{Fig. 2}$ | [1] | - | 120 | A |
| | | $V_{GS} = 10\text{ V}; T_{mb} = 25\text{ °C}; \text{Fig. 2}$ | [1] | - | 120 | A |
| I_{DM} | peak drain current | pulsed; $t_p \leq 10\text{ }\mu\text{s}; T_{mb} = 25\text{ °C}; \text{Fig. 3}$ | | - | 1609 | A |
| T_{stg} | storage temperature | | | -55 | 175 | °C |
| T_j | junction temperature | | | -55 | 175 | °C |
| $T_{sld(M)}$ | peak soldering temperature | | | - | 260 | °C |
| Source-drain diode | | | | | | |
| I_S | source current | $T_{mb} = 25\text{ °C}$ | [1] | - | 120 | A |
| I_{SM} | peak source current | pulsed; $t_p \leq 10\text{ }\mu\text{s}; T_{mb} = 25\text{ °C}$ | | - | 1609 | A |
| Avalanche ruggedness | | | | | | |
| $E_{DS(AL)S}$ | non-repetitive drain-source avalanche energy | $V_{GS} = 10\text{ V}; T_{j(\text{init})} = 25\text{ °C}; I_D = 120\text{ A}; V_{sup} \leq 30\text{ V}; R_{GS} = 50\text{ }\Omega; \text{unclamped}$ | | - | 1.9 | J |

[1] Continuous current is limited by package.

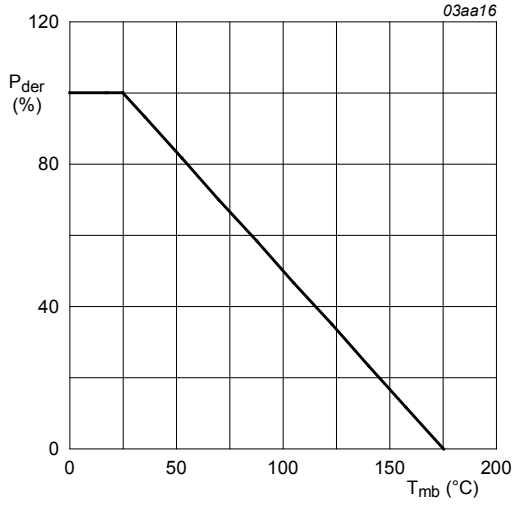


Fig. 1. Normalized total power dissipation as a function of mounting base temperature

$$P_{der} = \frac{P_{tot}}{P_{tot(25^{\circ}\text{C})}} \times 100\%$$

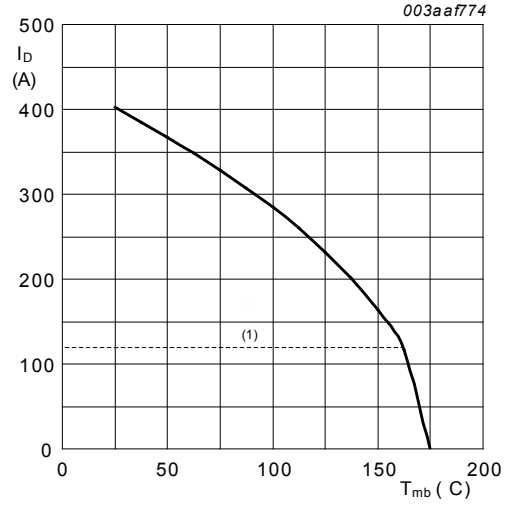


Fig. 2. Continuous drain current as a function of mounting base temperature.

$V_{GS} \geq 10\text{ V(1)}$ Capped at 120 A due to package

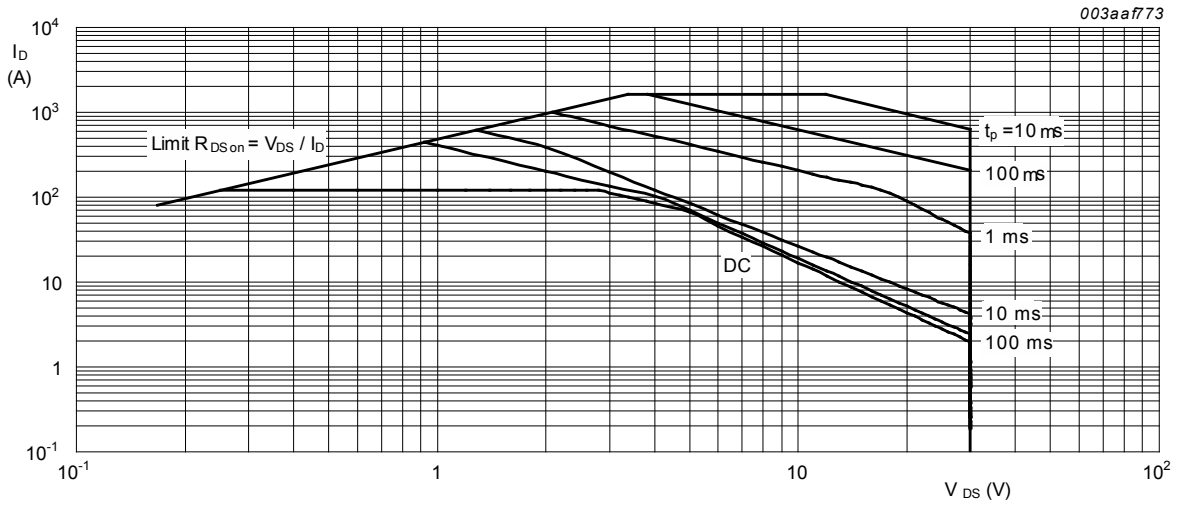


Fig. 3. Safe operating area; continuous and peak drain currents as a function of drain-source voltage

$T_{mb} = 25\text{ }^{\circ}\text{C}$; I_{DM} is a single pulse; Capped at 120 A due to package

9. Thermal characteristics

Table 6. Thermal characteristics

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|----------------|---|------------------------|-----|------|------|------|
| $R_{th(j-mb)}$ | thermal resistance from junction to mounting base | Fig. 4 | - | 0.22 | 0.44 | K/W |

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|---------------|---|----------------------|-----|-----|-----|------|
| $R_{th(j-a)}$ | thermal resistance from junction to ambient | Vertical in free air | - | 60 | - | K/W |

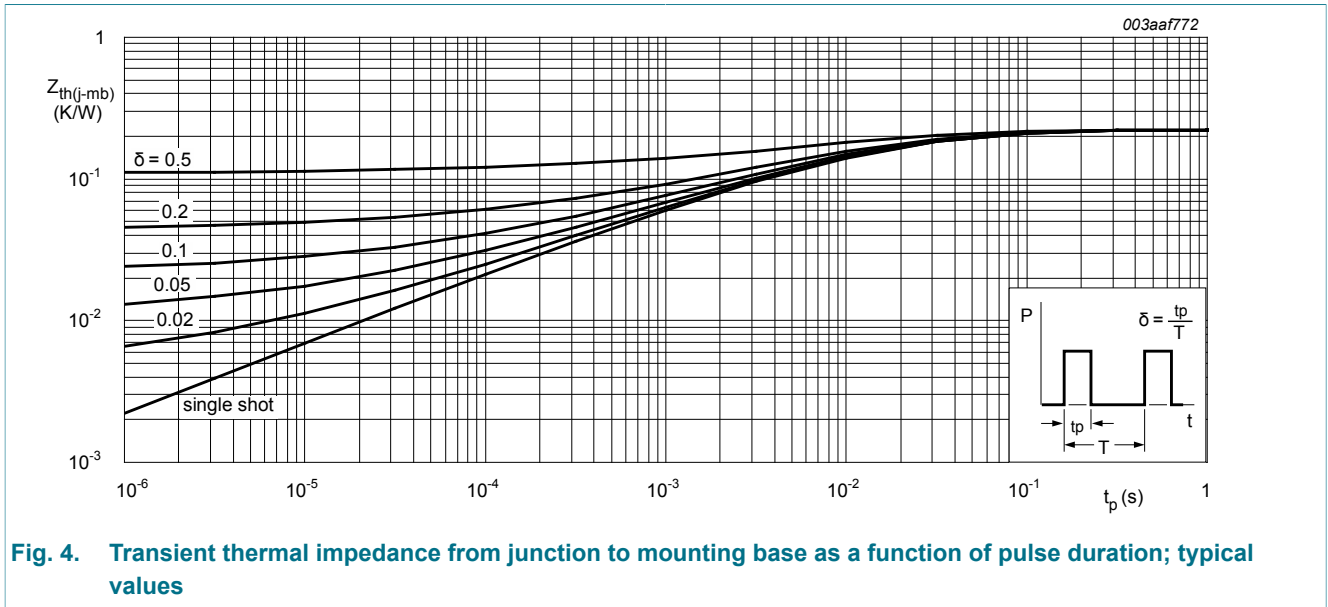


Fig. 4. Transient thermal impedance from junction to mounting base as a function of pulse duration; typical values

10. Characteristics

Table 7. Characteristics

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit | |
|-------------------------------|----------------------------------|---|-----|------|-----|---------|----|
| Static characteristics | | | | | | | |
| $V_{(BR)DSS}$ | drain-source breakdown voltage | $I_D = 250 \mu A; V_{GS} = 0 V; T_j = 25 \text{ }^\circ C$ | 30 | - | - | V | |
| | | $I_D = 250 \mu A; V_{GS} = 0 V; T_j = -55 \text{ }^\circ C$ | 27 | - | - | V | |
| $V_{GS(th)}$ | gate-source threshold voltage | $I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = 25 \text{ }^\circ C;$ Fig. 10; Fig. 11 | 1.3 | 1.7 | 2.2 | V | |
| | | $I_D = 2 \text{ mA}; V_{DS} = V_{GS}; T_j = 175 \text{ }^\circ C;$ Fig. 11 | 0.5 | - | - | V | |
| | | $I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = -55 \text{ }^\circ C;$ Fig. 11 | - | - | 2.5 | V | |
| I_{DSS} | drain leakage current | $V_{DS} = 30 \text{ V}; V_{GS} = 0 \text{ V}; T_j = 25 \text{ }^\circ C$ | - | 0.02 | 10 | μA | |
| | | $V_{DS} = 30 \text{ V}; V_{GS} = 0 \text{ V}; T_j = 175 \text{ }^\circ C$ | - | 250 | 500 | μA | |
| I_{GSS} | gate leakage current | $V_{GS} = 16 \text{ V}; V_{DS} = 0 \text{ V}; T_j = 25 \text{ }^\circ C$ | - | 10 | 100 | nA | |
| | | $V_{GS} = -16 \text{ V}; V_{DS} = 0 \text{ V}; T_j = 25 \text{ }^\circ C$ | - | 10 | 100 | nA | |
| R_{DSon} | drain-source on-state resistance | $V_{GS} = 10 \text{ V}; I_D = 25 \text{ A}; T_j = 25 \text{ }^\circ C;$ Fig. 12 | [1] | - | 1.1 | 1.3 | mΩ |

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|--------------------------------|-----------------------------------|---|-----|-------|-----|------|
| | | $V_{GS} = 4.5 \text{ V}; I_D = 25 \text{ A}; T_j = 25 \text{ }^\circ\text{C};$ Fig. 12 | - | 1.2 | 1.4 | mΩ |
| | | $V_{GS} = 10 \text{ V}; I_D = 25 \text{ A}; T_j = 175 \text{ }^\circ\text{C};$ Fig. 13; Fig. 12 | - | 2.1 | 2.5 | mΩ |
| | | $V_{GS} = 10 \text{ V}; I_D = 25 \text{ A}; T_j = 100 \text{ }^\circ\text{C};$ Fig. 13 | - | 1.5 | 1.8 | mΩ |
| R_G | gate resistance | $f = 1 \text{ MHz}$ | - | 1.1 | - | Ω |
| Dynamic characteristics | | | | | | |
| $Q_{G(\text{tot})}$ | total gate charge | $I_D = 75 \text{ A}; V_{DS} = 15 \text{ V}; V_{GS} = 10 \text{ V};$ Fig. 14; Fig. 15 | - | 243 | - | nC |
| | | $I_D = 0 \text{ A}; V_{DS} = 0 \text{ V}; V_{GS} = 10 \text{ V};$ Fig. 14; Fig. 15 | - | 223 | - | nC |
| | | $I_D = 75 \text{ A}; V_{DS} = 15 \text{ V}; V_{GS} = 4.5 \text{ V};$ Fig. 14; Fig. 15 | - | 118 | - | nC |
| Q_{GS} | gate-source charge | | - | 39 | - | nC |
| $Q_{GS(\text{th})}$ | pre-threshold gate-source charge | | - | 22 | - | nC |
| $Q_{GS(\text{th-pl})}$ | post-threshold gate-source charge | | - | 17 | - | nC |
| Q_{GD} | gate-drain charge | | - | 37 | - | nC |
| $V_{GS(\text{pl})}$ | gate-source plateau voltage | $V_{DS} = 15 \text{ V};$ Fig. 14; Fig. 15 | - | 2.8 | - | V |
| C_{iss} | input capacitance | $V_{DS} = 15 \text{ V}; V_{GS} = 0 \text{ V}; f = 1 \text{ MHz};$ $T_j = 25 \text{ }^\circ\text{C};$ Fig. 16 | - | 14850 | - | pF |
| C_{oss} | output capacitance | | - | 2799 | - | pF |
| C_{rss} | reverse transfer capacitance | | - | 1215 | - | pF |
| $t_{d(\text{on})}$ | turn-on delay time | $V_{DS} = 15 \text{ V}; R_L = 0.2 \text{ } \Omega; V_{GS} = 4.5 \text{ V};$ $R_{G(\text{ext})} = 5 \text{ } \Omega; I_D = 75 \text{ A}; T_j = 25 \text{ }^\circ\text{C}$ | - | 95 | - | ns |
| t_r | rise time | | - | 213 | - | ns |
| $t_{d(\text{off})}$ | turn-off delay time | | - | 199 | - | ns |
| t_f | fall time | | - | 115 | - | ns |
| Source-drain diode | | | | | | |
| V_{SD} | source-drain voltage | $I_S = 25 \text{ A}; V_{GS} = 0 \text{ V}; T_j = 25 \text{ }^\circ\text{C};$ Fig. 17 | - | 0.8 | 1.2 | V |
| t_{rr} | reverse recovery time | $I_S = 25 \text{ A}; di_S/dt = -100 \text{ A}/\mu\text{s}; V_{GS} = 0 \text{ V};$ $V_{DS} = 15 \text{ V}$ | - | 67 | - | ns |
| Q_r | recovered charge | | - | 123 | - | nC |

[1] Measured 3 mm from package.

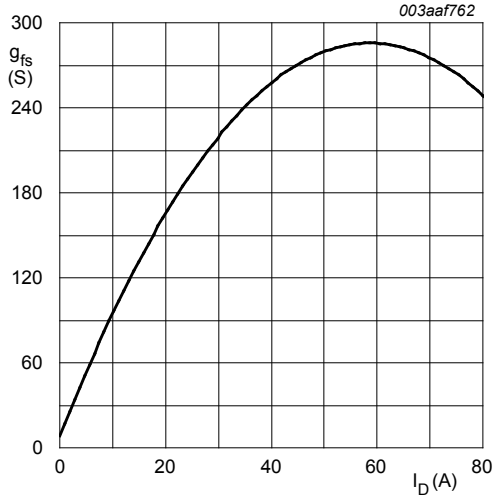


Fig. 5. Forward transconductance as a function of drain current; typical values

$$T_j = 25^\circ\text{C}; V_{DS} = 15\text{V}$$

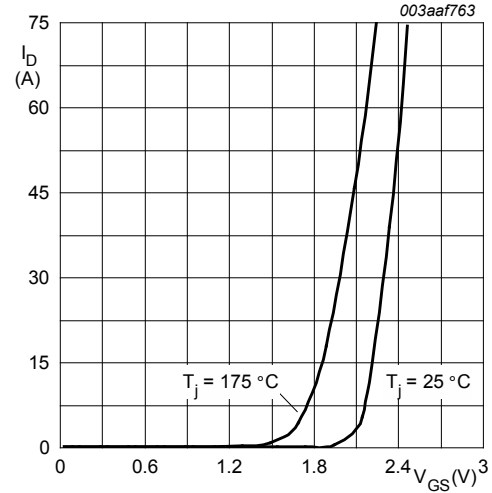


Fig. 6. Transfer characteristics: drain current as a function of gate-source voltage; typical values

$$V_{DS} = 15\text{V}$$

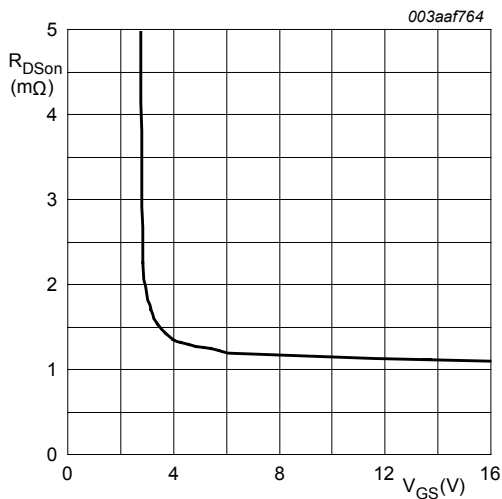


Fig. 7. Drain-source on-state resistance as a function of gate-source voltage; typical values

$$T_j = 25^\circ\text{C}; I_D = 25\text{A}$$

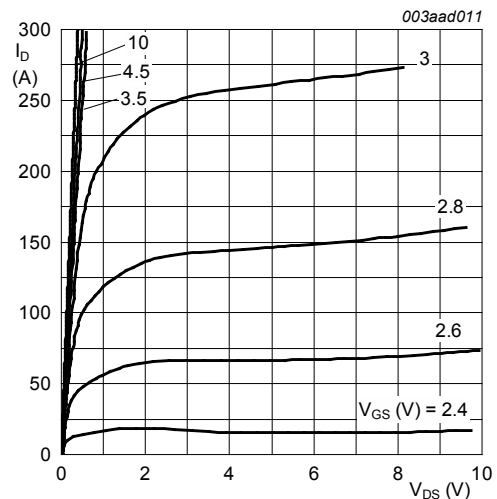


Fig. 8. Output characteristics: drain current as a function of drain-source voltage; typical values

$$T_j = 25^\circ\text{C}; t_p = 300\mu\text{s}$$

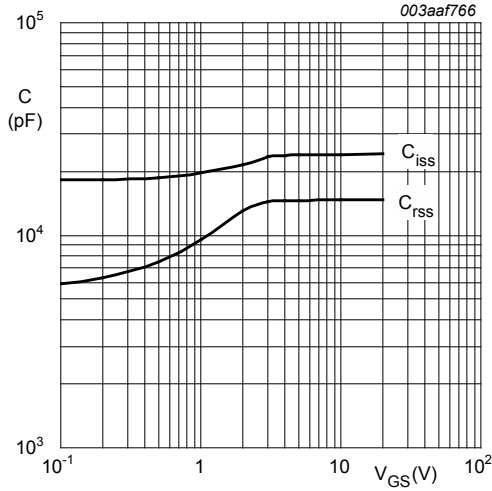


Fig. 9. Input and reverse transfer capacitances as a function of gate-source voltage; typical values

$$V_{DS} = 0V; f = 1MHz$$

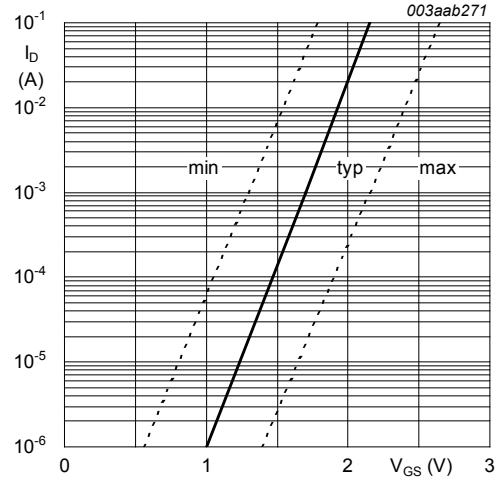


Fig. 10. Sub-threshold drain current as a function of gate-source voltage

$$T_j = 25^\circ C; V_{DS} = 5V$$

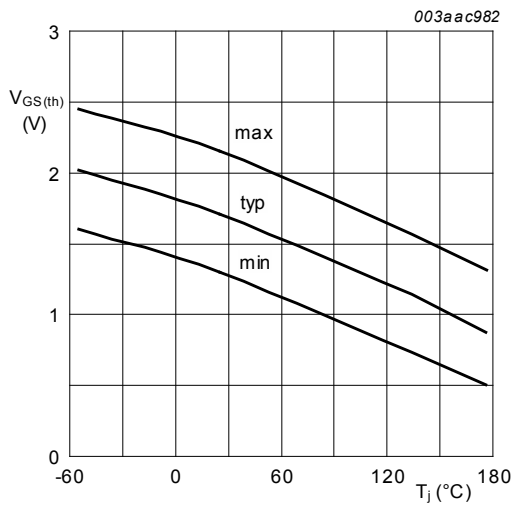


Fig. 11. Gate-source threshold voltage as a function of junction temperature

$$I_D = 1mA; V_{DS} = V_{GS}$$

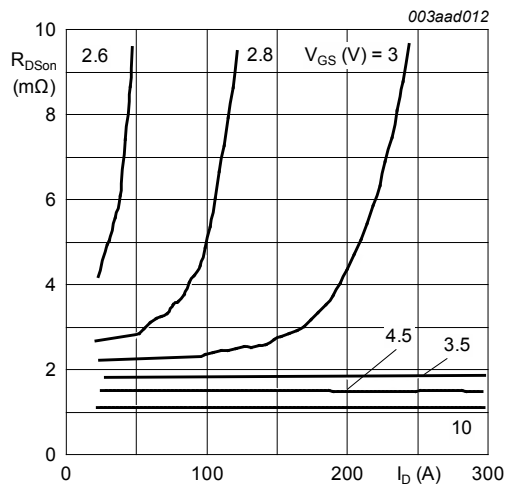


Fig. 12. Drain-source on-state resistance as a function of drain current; typical values

$$T_j = 25^\circ C$$

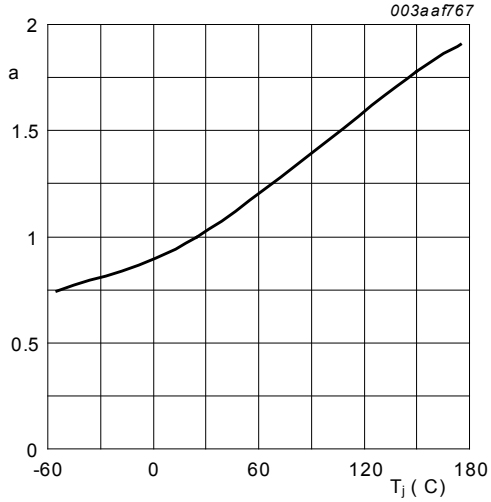


Fig. 13. Normalized drain-source on-state resistance factor as a function of junction temperature

$$a = \frac{R_{DS(on)}}{R_{DS(on)25^{\circ}C}}$$

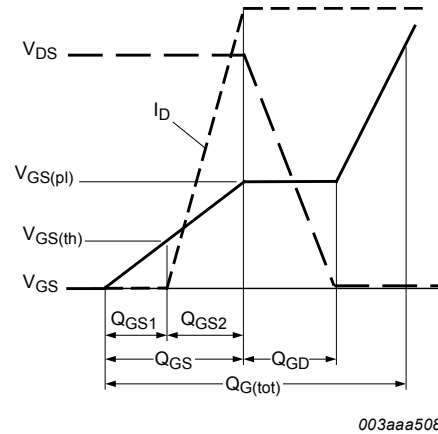


Fig. 14. Gate charge waveform definitions

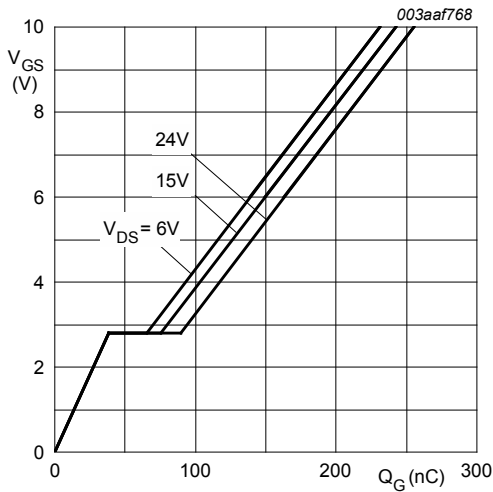


Fig. 15. Gate-source voltage as a function of gate charge; typical values

$$T_j = 25^{\circ}C; I_D = 25A$$

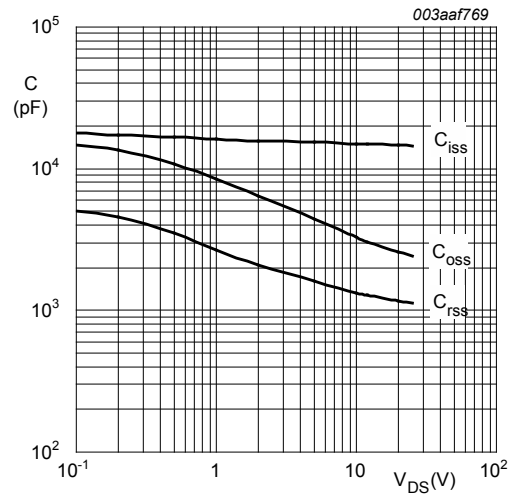


Fig. 16. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values

$$V_{GS} = 0V; f = 1MHz$$

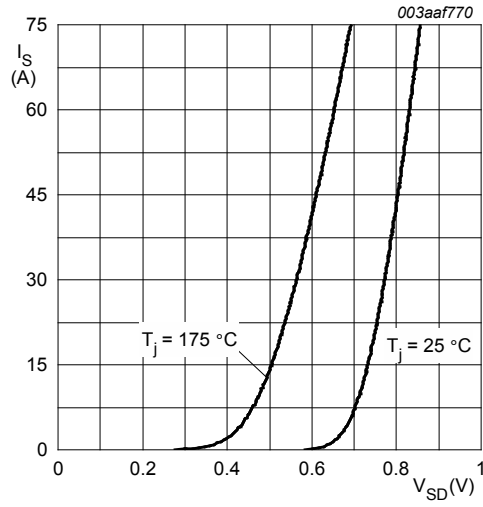


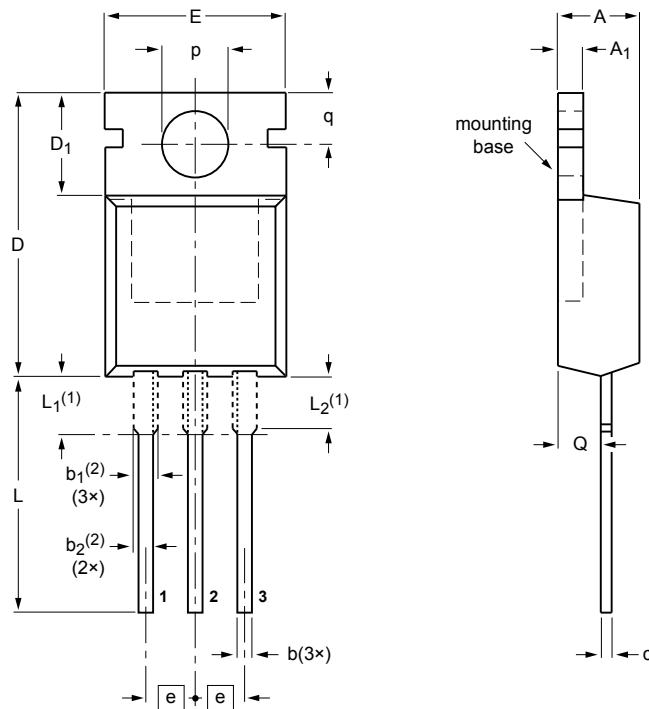
Fig. 17. Source (diode forward) current as a function of source-drain (diode forward) voltage; typical values

$$V_{GS} = 0V$$

11. Package outline

Plastic single-ended package; heatsink mounted; 1 mounting hole; 3-lead TO-220AB

SOT78



DIMENSIONS (mm are the original dimensions)

| UNIT | A | A ₁ | b | b ₁ (2) | b ₂ (2) | c | D | D ₁ | E | e | L | L ₁ (1) | L ₂ (1) max. | p | q | Q |
|------|------------|----------------|------------|--------------------|--------------------|------------|--------------|----------------|-------------|------|--------------|--------------------|-------------------------|------------|------------|------------|
| mm | 4.7 4.1 | 1.40 1.25 | 0.9 0.6 | 1.6 1.0 | 1.3 1.0 | 0.7 0.4 | 16.0 15.2 | 6.6 5.9 | 10.3 9.7 | 2.54 | 15.0 12.8 | 3.30 2.79 | 3.0 | 3.8 3.5 | 3.0 2.7 | 2.6 2.2 |

Notes

- Lead shoulder designs may vary.
- Dimension includes excess dambar.

| OUTLINE VERSION | REFERENCES | | | EUROPEAN PROJECTION | ISSUE DATE |
|-----------------|------------|-----------------|-------|---------------------|----------------------|
| | IEC | JEDEC | JEITA | | |
| SOT78 | | 3-lead TO-220AB | SC-46 | | 08-04-23 08-06-13 |

Fig. 18. Package outline TO-220AB (SOT78)

12. Legal information

12.1 Data sheet status

| Document status [1][2] | Product status [3] | Definition |
|--------------------------------|--------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

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- [2] The term 'short data sheet' is explained in section "Definitions".
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